

Silicon NPN Power Transistors

2SC3090

DESCRIPTION

- With TO-3PN package
- High breakdown voltage ($V_{CBO} = 800V$)
- Fast switching speed
- Wide ASO (Safe Operating Area)

APPLICATIONS

- 500V/10A Switching Regulator Applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

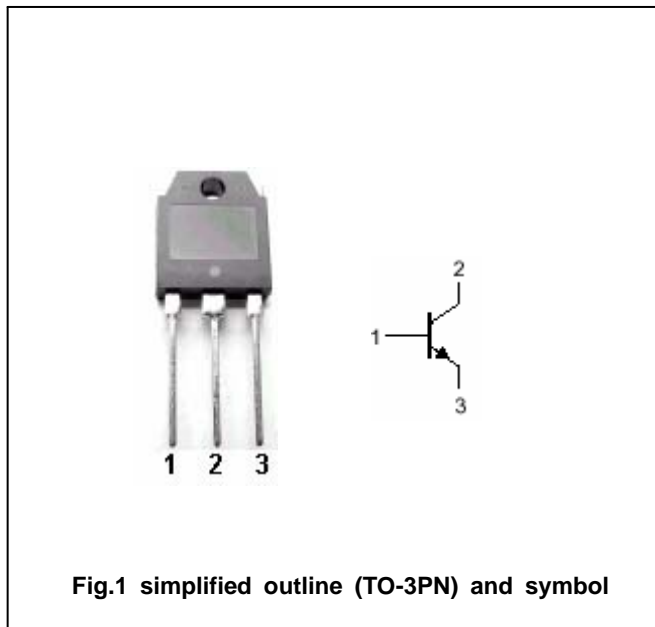


Fig.1 simplified outline (TO-3PN) and symbol

Absolute maximum ratings ($T_a=25^\circ C$)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	800	V
V_{CEO}	Collector-emitter voltage	Open base	500	V
V_{EBO}	Emitter-base voltage	Open collector	7	V
I_C	Collector current		10	A
I_{CM}	Collector current-peak		20	A
I_B	Base current		4	A
P_C	Collector power dissipation	$T_a=25$	2.5	W
		$T_C=25$	100	
T_j	Junction temperature		150	
T_{stg}	Storage temperature		-55~150	

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CHARACTERISTICS

T_j=25 unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =5mA ; R _{BE} =	500			V
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =1mA ; I _E =0	800			V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =1mA ; I _C =0	7			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =6A ; I _B =1.2A			1.0	V
V _{BEsat}	Base-emitter saturation voltage	I _C =6A ; I _B =1.2A			1.5	V
I _{CBO}	Collector cut-off current	V _{CB} =500V ; I _E =0			10	μA
I _{EBO}	Emitter cut-off current	V _{EB} =5V ; I _C =0			10	μA
h _{FE-1}	DC current gain	I _C =1.2A ; V _{CE} =5V	15		50	
h _{FE-2}	DC current gain	I _C =6A ; V _{CE} =5V	8			
C _{OB}	Output capacitance	I _E =0 ; V _{CB} =10V ; f=1MHz		160		pF
f _T	Transition frequency	I _C =1.2A ; V _{CE} =10V		18		MHz

Switching times

t _{on}	Turn-on time	I _C =7A ; I _{B1} =-I _{B2} =1.4A R _L =28.6 Ω , V _{CC} =200V			1.0	μs
t _s	Storage time				3.0	μs
t _f	Fall time				1.0	μs

◆ h_{FE-1} classifications

L	M	N
15-30	20-40	30-50

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PACKAGE OUTLINE

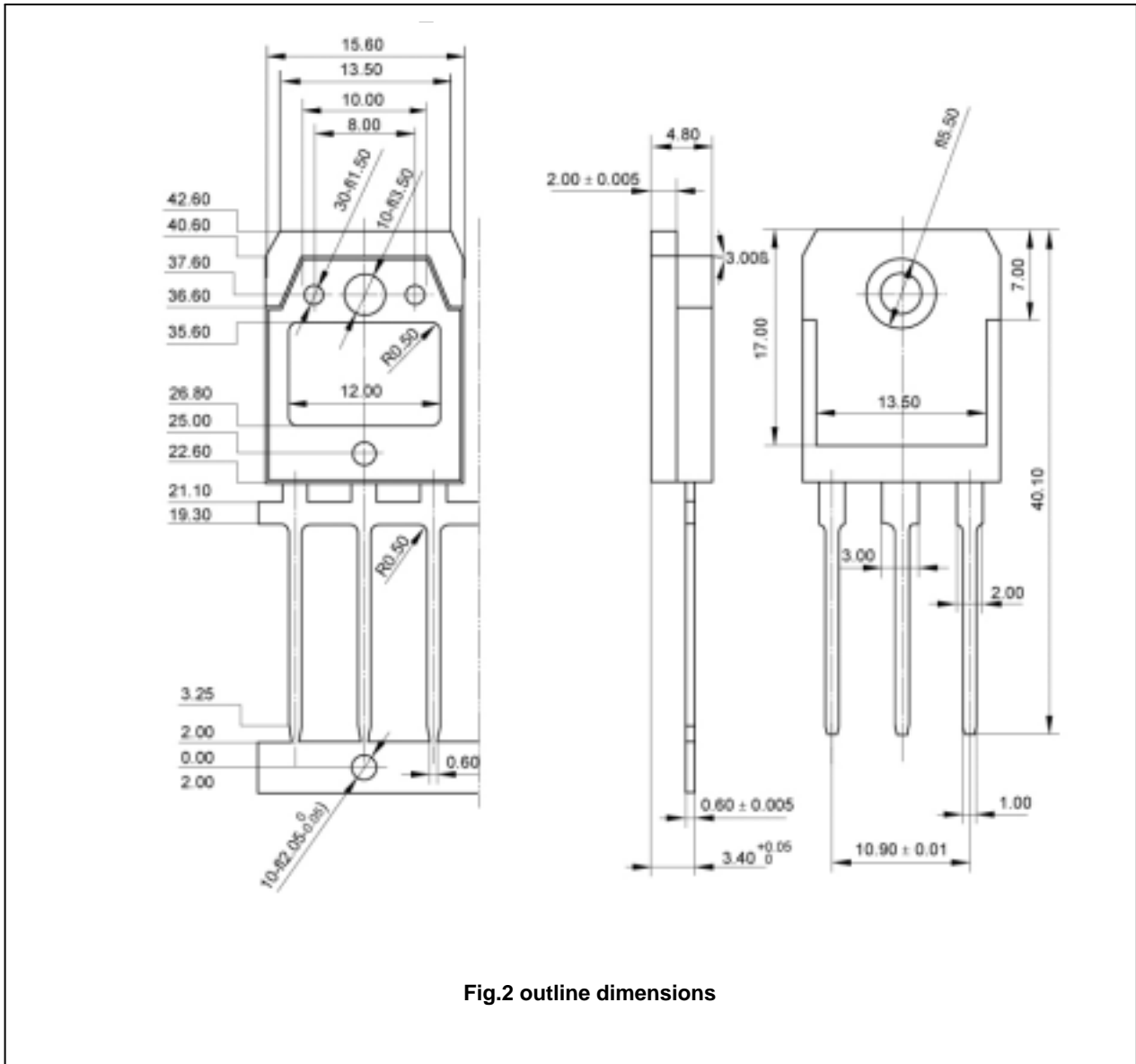


Fig.2 outline dimensions

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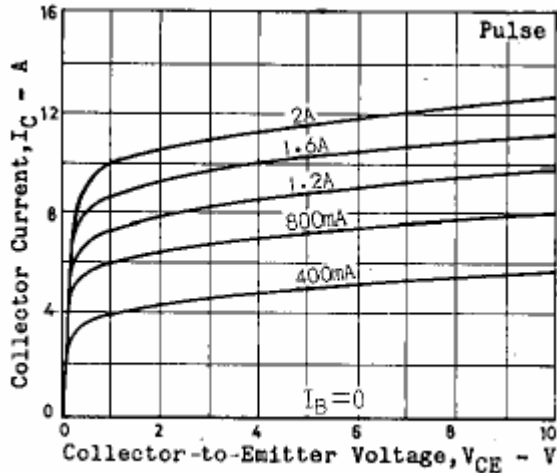


Fig.3 Static Characteristic

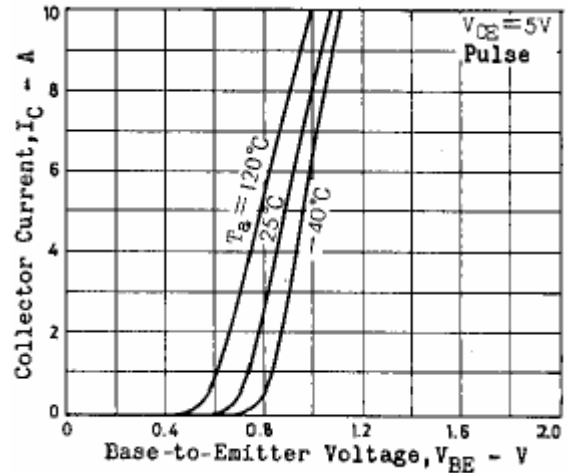


Fig.4 Base-Emitter On Voltage

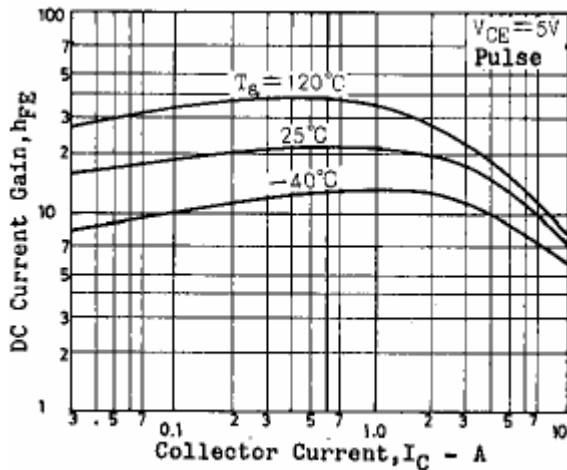


Fig.5 DC current Gain

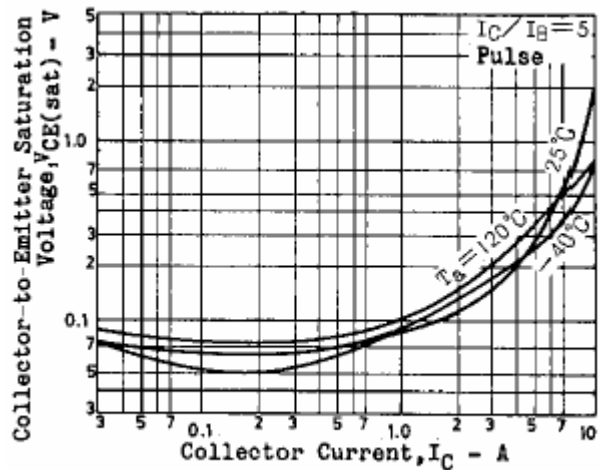


Fig.6 Collector-Emmitter Saturation Voltage

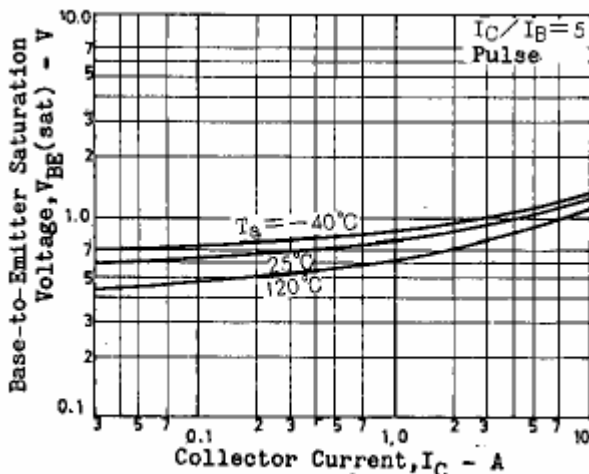


Fig.7 Base-Emmitter Saturation Voltage

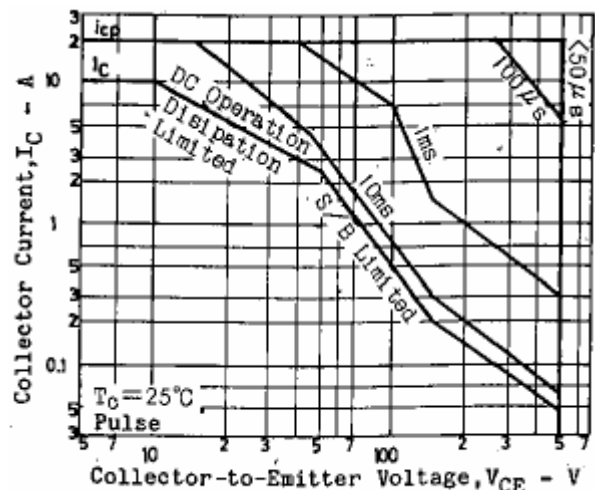


Fig.8 Safe Operating Area